

## Digital Synchronous Rectifier Controller Optimized for Wide Range Outputs with Optional Active Voltage Position Control

### 1 Description

The iW676 is an advanced synchronous rectifier (SR) controller with an integrated MOSFET driver for discontinuous mode flyback converters. The device works with an external power MOSFET to replace the main rectifying diode on the secondary of a flyback converter, improving efficiency by reducing conduction losses on the secondary. The iW676 uses lossless sensing by monitoring the voltage across the synchronous MOSFET to determine when to switch the FET, further improving efficiency. Dialog's digital adaptive turn-off control technology minimizes turn-off deadtime, eliminating the need for an additional Schottky diode that is typically needed in parallel with the synchronous MOSFET in conventional synchronous rectifiers.

The iW676 has the ability to work at output voltages as high as 25V and as low as 3V under all conditions to accommodate a wide array of power supplies. It can sense drain voltages up to 100V, eliminating the need for an external clamping circuit in applications with multi-level output voltage applications up to 12V. A unique internal regulator circuit enables the iW676 to operate down to very low voltages on the output of the power supply, optimizing the device for Direct Charging applications down to sub-3V levels.

The iW676-3X/3XC integrates Dialog's unique Active Voltage Positioning (AVP) control for fast dynamic load response and very low no-load power consumption (non-rapid charge applications), without increasing the package size or pin count.

### 2 Features

- Supports system output voltages from 3V to 25V in multi-level output voltage and current applications
  - » Integrated pulse linear regulator (PLR) enables high efficiency SR operation down to 3V under all load conditions and below 2.4V under constant current (CC) mode condition
    - » Supports Direct Charge down to sub-3V levels
  - » Wide  $V_{IN}$  pin operating voltage up to 25V
- High voltage Drain sensing up to 100V with no additional external clamping circuits required
- 6-pin SOT23 package
- Digital adaptive turn-off control minimizes dead-time and eliminates the parallel Schottky diode
- Lossless MOSFET  $V_{DS}$  sensing for SR timing control
- Optimized 5V MOSFET gate driver
- Intelligent low power management achieves ultra-low no-load operating current
- Built-in Active Voltage Positioning (AVP) to provide fast system output voltage transient detection with no additional pins or external components required. (iW676-3X/3XC options)

### 3 Applications

- Compact AC/DC adapters/chargers for media tablets and smart phones

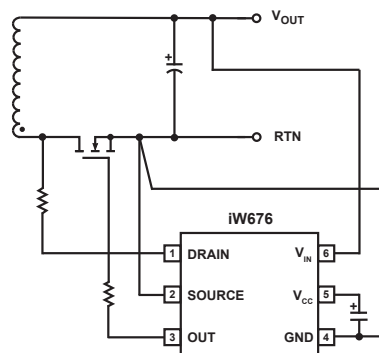
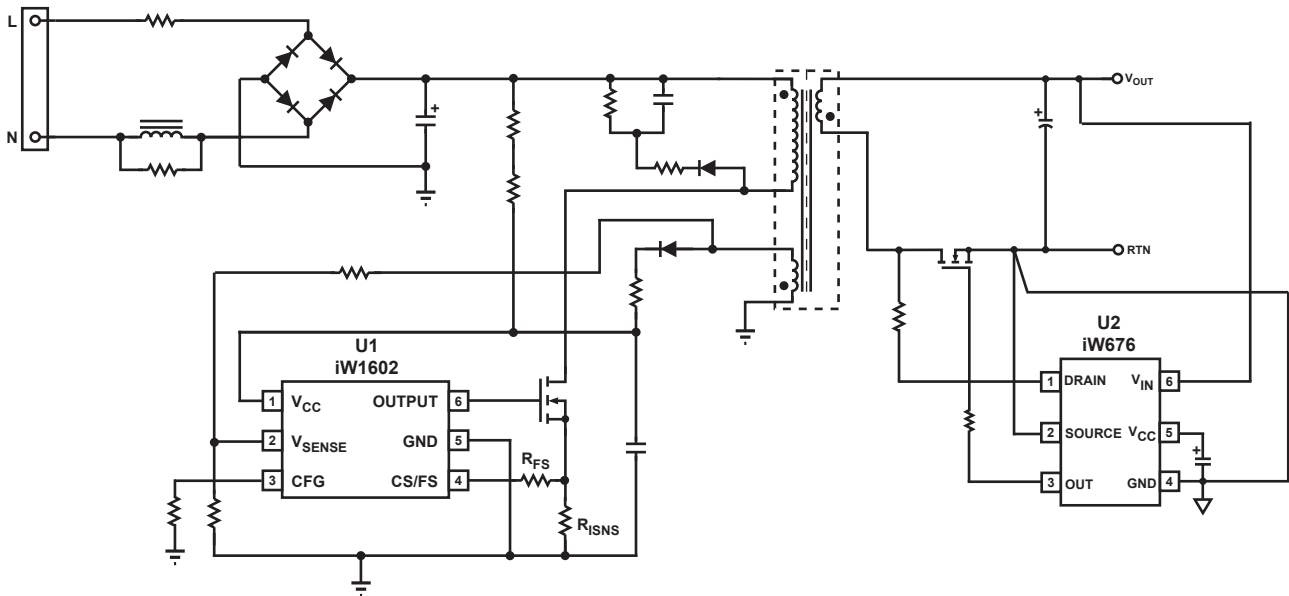
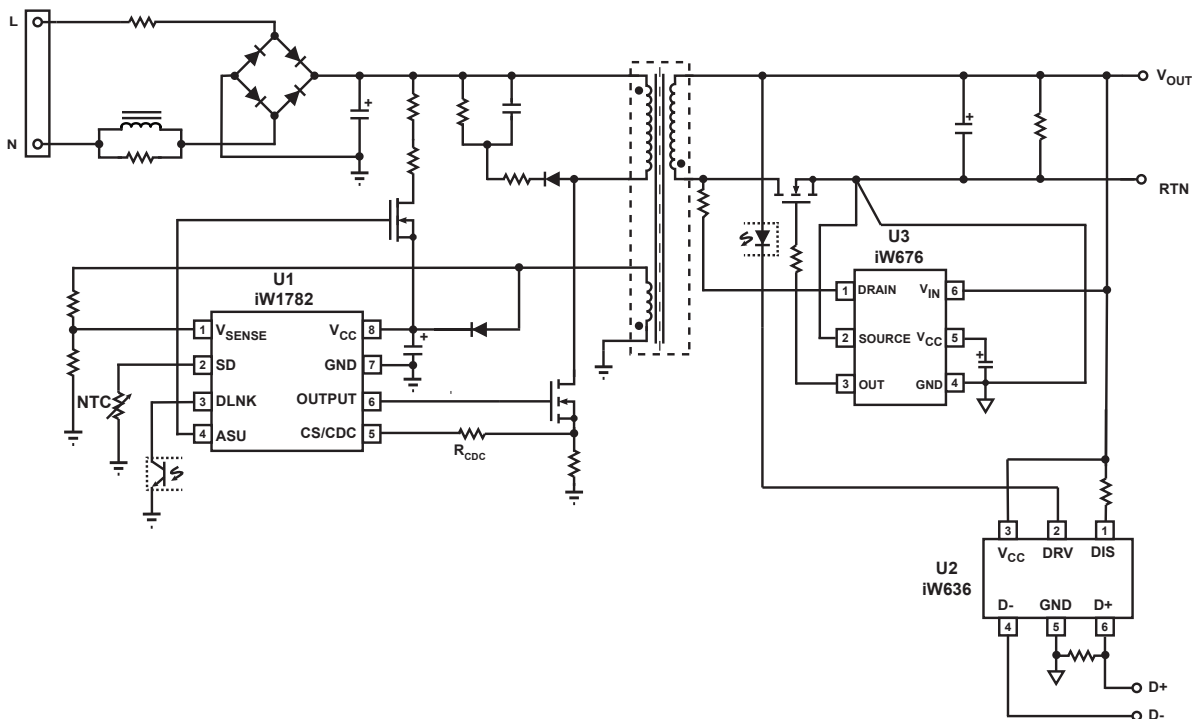


Figure 3.1 : iW676 Typical Application Circuit

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**Figure 3.2 : iW676 Typical Application Circuit Using iW1602 as the Primary-Side Controller (Achieving < 30mW No-Load Power Consumption in 5V, 2.5A Adapter Designs with Fast Dynamic Load Response, and Supporting Constant Current Operation at Low System Output)**



**Figure 3.3 : iW676 Typical Application Circuit for Multi-Level Output Voltage and Current (Using iW1782 as Primary-Side Controller and iW636 as Secondary-Side Controller for Qualcomm® Quick Charge™ 3.0) (Achieving < 20mW No-Load Power Consumption)**

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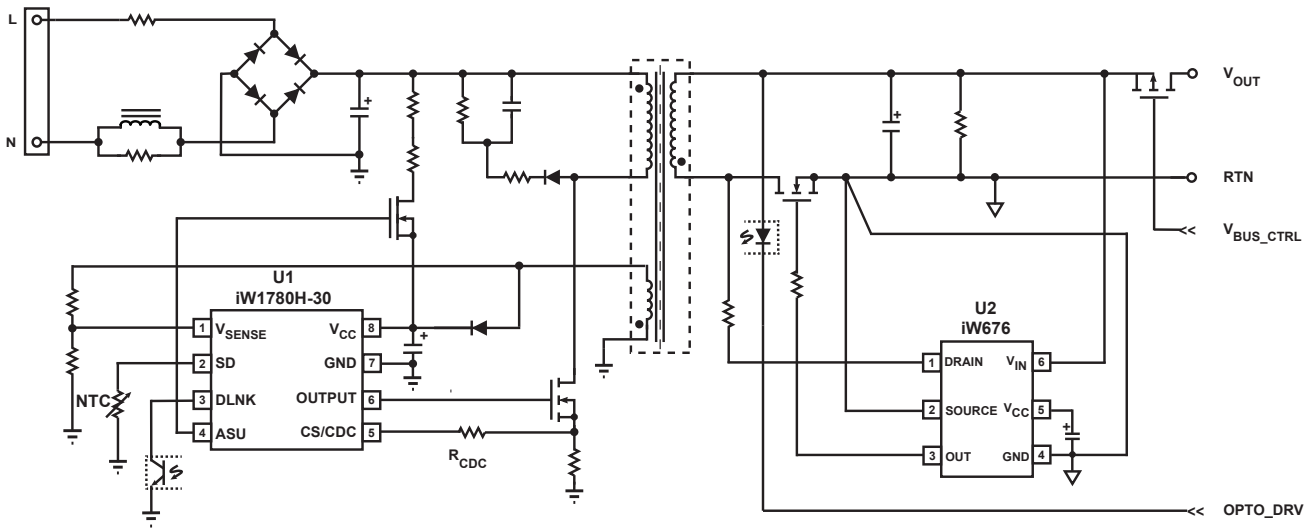


Figure 3.4 : Direct Charge Application with  $V_{BUS}$  Switch (Using Secondary-Side IC Interfacing MD with D+/D- or CC1/CC2 for Direct Charge and iW676 as SR Controller)

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### 4 Pinout Description

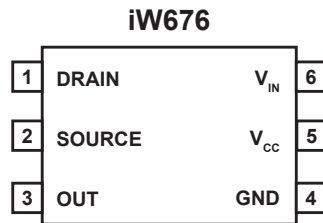


Figure 4.1 : 6-Pin SOT23 Package

| Pin No. | Pin Name | Type         | Pin Description   |
|---------|----------|--------------|---|
| 1       | DRAIN    | Analog Input | Synchronous rectifier MOSFET drain voltage sensing and the Pulse Linear Regulator (PLR) input. For iW676-3X/3XC, it is also the secondary-side Active Voltage Positioning function input and output.  |
| 2       | SOURCE   | Analog input | Synchronous rectifier MOSFET source voltage sensing input. In the iW676-xxC, this pin is internally connected to GND.   |
| 3       | OUT      | Output       | Synchronous rectifier MOSFET driver.  |
| 4       | GND      | Ground       | Ground.   |
| 5       | $V_{CC}$ | Power Input  | Output of internal LDO and PLR. It provides bias voltage for the internal logic circuit and the MOSFET driver. Connect this pin to a capacitor.   |
| 6       | $V_{IN}$ | Analog Input | Input of internal LDO and system output voltage sensing circuit. Connect to adapter/charger output for bias voltage. The internal LDO clamps the $V_{CC}$ voltage at 5V when $V_{IN} > 5V$ . $V_{IN}$ is also the input for the PLR enable comparator and the SR enable comparator. |

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### 5 Absolute Maximum Ratings

Absolute maximum ratings are the parameter values or ranges which can cause permanent damage if exceeded. For maximum safe operating conditions, refer to Electrical Characteristics in Section 6.

| Parameter   | Symbol        | Value       | Units                       |
|---|---------------|-------------|-----------------------------|
| $V_{IN}$ DC supply voltage range (pin 6, $I_{CC} = 15\text{mA}$ max)    | $V_{IN}$      | -0.3 to 33  | V                           |
| Continuous DC supply current at $V_{IN}$ pin ( $V_{IN} = 30\text{V}$ )  | $I_{VO}$      | 15          | mA                          |
| Continuous DC supply current at $V_{CC}$ pin ( $V_{CC} = 5.5\text{V}$ ) | $I_{VCC}$     | 15          | mA                          |
| Gate peak output current  | $I_G$         | $\pm 3$     | A                           |
| DRAIN pin voltage (Note 1)  | $V_D$         | -1.5 to 100 | V                           |
| DRAIN pin peak current  | $I_{DRAIN}$   | -40 to 300  | mA                          |
| SOURCE pin voltage (Note 2)   | $V_{SOURCE}$  | -0.6 to 1   | V                           |
| $V_{CC}$ pin voltage  | $V_{CC}$      | -0.6 to 6   | V                           |
| Junction temperature  | $T_J$         | -40 to 150  | $^{\circ}\text{C}$          |
| Storage temperature   |               | -65 to 150  | $^{\circ}\text{C}$          |
| Thermal resistance junction-to-ambient                                  | $\theta_{JA}$ | 190         | $^{\circ}\text{C}/\text{W}$ |
| ESD rating per JEDEC JS-001-2017  |               | $\pm 2,000$ | V                           |

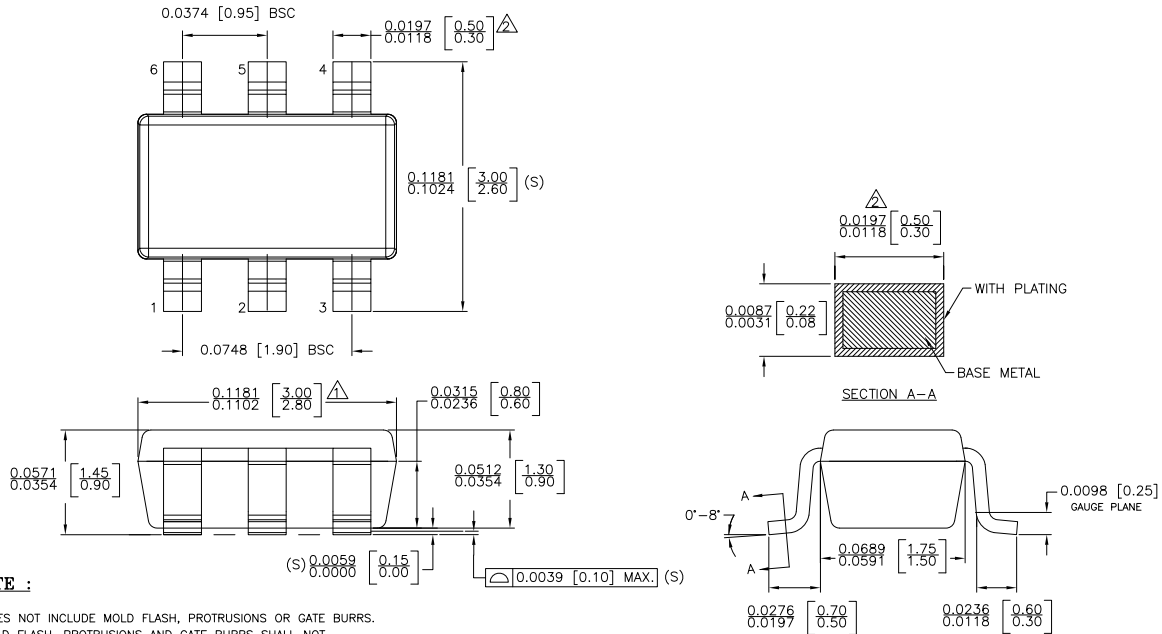
#### Notes:

Note 1: The DRAIN pin voltage should not be below -0.6V for more than 500ns.

Note 2: Only applies to iW676-XX. In iW676-XXC, this pin is internally connected to GND.


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### 6 Physical Dimensions



#### NOTE :

1. DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS AND GATE BURRS SHALL NOT EXCEED 0.127 MM PER SIDE.
2. DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED 0.127 MM PER SIDE.
3. DIE IS FACING UP FOR MOLD. DIE IS FACING DOWN FOR TRIM/FORM.
4. THIS PART IS COMPLIANT WITH EIAJ SPECIFICATION SC74A AND JEDEC SPECIFICATION MO-178AB.
5. LEAD SPAN/STAND OFF HEIGHT/COPLANARITY ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
6. CONTROLLING DIMENSIONS IN INCHES. [mm]

|   |                               |                        |
|---|-------------------------------|------------------------|
|  |                               |                        |
| STATUS:<br>RELEASED   |                               | SCALE:<br>DO NOT SCALE |
| TERMINAL FINISH:<br>100% Sn or NiPdAu (PPF)   |                               |                        |
| TITLE:<br>6 SOT23 PACKAGE OUTLINE   |                               |                        |
| REV:<br>A   | REVISION NOTE:<br>NEW DRAWING | DATE:<br>02-MAR-2015   |

### 7 Ordering Information

| Part no.  | Options  | Package | Description                |
|-----------|--|---------|----------------------------|
| iW676-00  | No Active Voltage Positioning (AVP) function<br>Not Recommended for New Designs, please use the iW676-00C  | SOT23   | Tape & Reel <sup>(1)</sup> |
| iW676-00C | No Active Voltage Positioning (AVP) function<br>Recommended for New Designs  | SOT23   | Tape & Reel <sup>(1)</sup> |
| iW676-30  | With secondary Active Voltage Positioning (AVP) function, under-voltage threshold ( $V_{UV}$ ) = 4.75V <sup>(2)</sup> . Not recommended for new designs, please use the iW676-30C. | SOT23   | Tape & Reel <sup>(1)</sup> |
| iW676-30C | With secondary Active Voltage Positioning (AVP) function, under-voltage threshold ( $V_{UV}$ ) = 4.75V <sup>(2)</sup> . Recommended for new designs.                               | SOT23   | Tape & Reel <sup>(1)</sup> |
| iW676-32  | With secondary Active Voltage Positioning (AVP) function, under-voltage threshold ( $V_{UV}$ ) = 11.2V <sup>(2)</sup>  | SOT23   | Tape & Reel <sup>(1)</sup> |

#### Notes:

Note 1: Tape and reel packing quantity is 3,000/reel. Minimum packing quantity is 3,000.

Note 2: For availability of additional  $V_{UV}$  options, please contact marketing.

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